FAIRCHILD

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74LCX06 Low Voltage Hex Inverter/Buffer with Open Drain Outputs

Features

- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 3.7ns t_{PD} max. (V_{CC} = 3.3V), 10µA I_{CC} max.
- Power down high impedance inputs and outputs
- ±24mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds 500mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V

General Description

The LCX06 contains six inverters/buffers. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The outputs of the LCX06 are open drain and can be connected to other open drain outputs to implement active LOW wire AND or active HIGH wire OR functions.

The 74LCX06 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

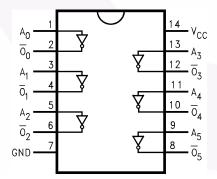
Ordering Information

Order Number	Package Number	Package Description
74LCX06M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LCX06SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX06MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram

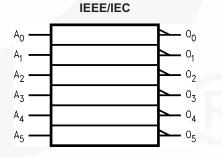


Pin Description

Pin Names	Description
A _n , B _n	Inputs
Ōn	Outputs

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Logic Symbol



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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
VI	DC Input Voltage	-0.5V to +7.0V
V _O	DC Output Voltage, Output in HIGH or LOW State ⁽¹⁾	-0.5V to +7.0V
I _{IK}	DC Input Diode Current, V _I < GND	–50mA
I _{OK}	DC Output Diode Current	
	V _O < GND	–50mA
	V _O > V _{CC}	+50mA
Ι _Ο	DC Output Sink Current	+50mA
I _{CC}	DC Supply Current per Supply Pin	±100mA
I _{GND}	DC Ground Current per Ground Pin	±100mA
T _{STG}	Storage Temperature	–65°C to +150°C

Note:

1. I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions⁽²⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
VI	Input Voltage	0	5.5	V
V _O	Output Voltage	0	5.5	V
I _{OL}	Output Current			
	$V_{CC} = 3.0V - 3.6V$		+24	mA
	$V_{CC} = 2.7V - 3.0V$		+12	
	$V_{CC} = 2.3V - 2.7V$		+8	
T _A	Free-Air Operating Temperature	-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

Note:

2. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

				T _A = -40°C to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Max.	Units
V _{IH}	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6		2.0		
V _{IL}	LOW Level Input Voltage	2.3–2.7			0.7	V
		2.7–3.6			0.8	
V _{OL}	LOW Level Output Voltage	2.3–3.6	I _{OL} = 100μA		0.2	V
		2.3	I _{OL} = 8mA		0.6	
		2.7	$I_{OL} = 12mA$		0.4	
		3.0	I _{OL} = 16mA		0.4	
			$I_{OL} = 24mA$		0.55	
I _I	Input Leakage Current	2.3–3.6	$0 \le V_I \le 5.5V$		±5.0	μA
I _{OFF}	Power-Off Leakage Current	0	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$		10	μA
I _{CC}	Quiescent Supply Current	2.3–3.6	$V_{I} = V_{CC}$ or GND		10	μA
			$3.6V \le V_I \le 5.5V$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	2.3–3.6	$V_{\rm IH} = V_{\rm CC} - 0.6V$		500	μA
I _{OHZ}	Off State Current	2.0–3.6	$V_0 = 5.5V$		10	μA

AC Electrical Characteristics

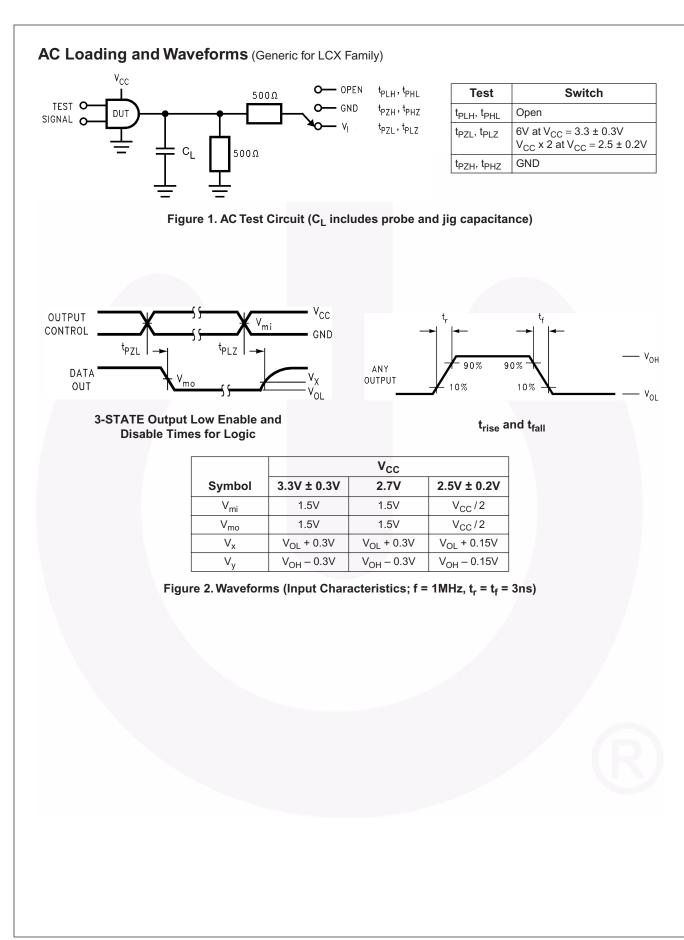
				$T_A = -40^{\circ}C$ to +85°C, $R_L = 500\Omega$						
			V	$\begin{array}{c} V_{CC}=3.3V\pm0.3V,\\ C_{L}=50pF \end{array}$		$V_{CC} = 2.7V,$ $C_L = 50pF$		$V_{CC} = 2.5V \pm 0.2V,$ $C_{L} = 30pF$		
Symb	loc	Parameter		Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PZL} , t _l	PLZ	Propagation Delay Tim	ie	0.8	3.7	1.0	4.1	0.8	3.5	ns

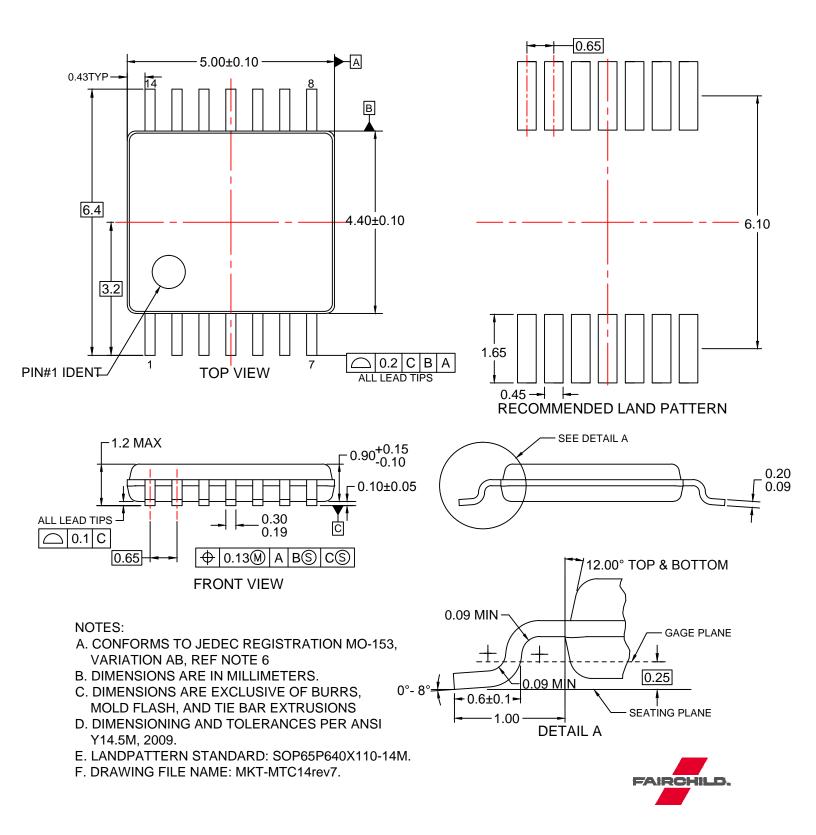
Dynamic Switching Characteristics

				T _A = 25°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50$ pF, $V_{IH} = 3.3$ V, $V_{IL} = 0$ V	0.9	V
		2.5	$C_L = 30$ pF, $V_{IH} = 2.5$ V, $V_{IL} = 0$ V	0.7	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50$ pF, $V_{IH} = 3.3$ V, $V_{IL} = 0$ V	-0.8	V
		2.5	$C_L = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V$	-0.6	

Capacitance

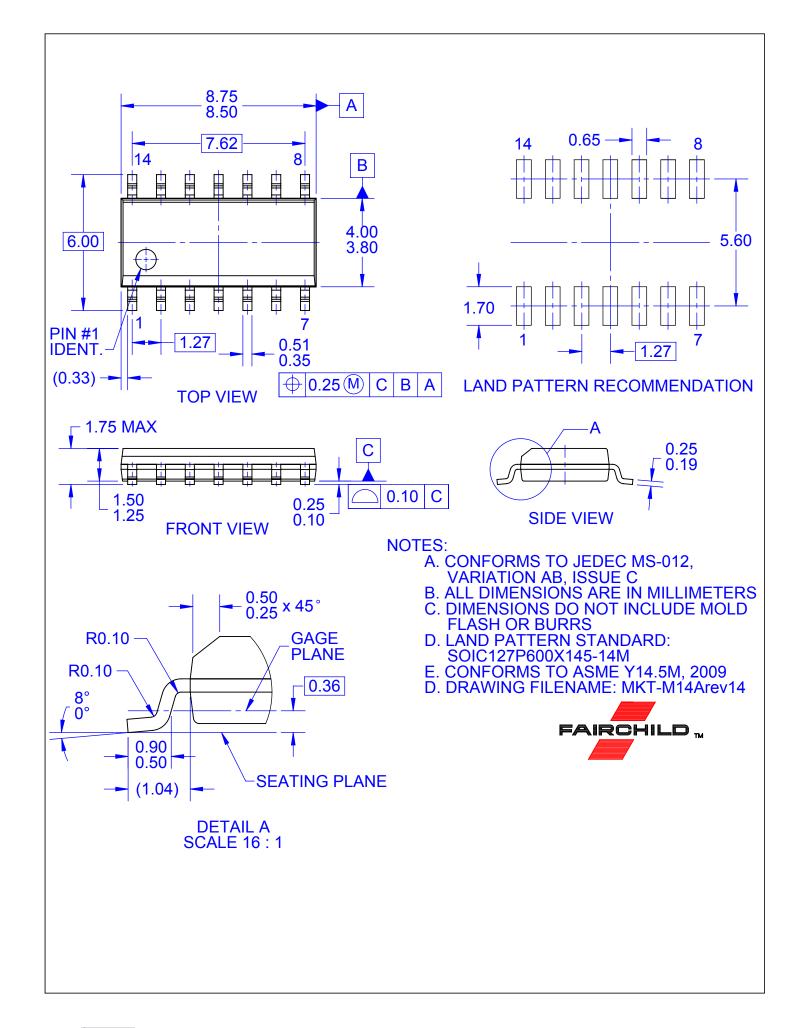
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3$ V, $V_I = 0$ V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10MHz	25	pF





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